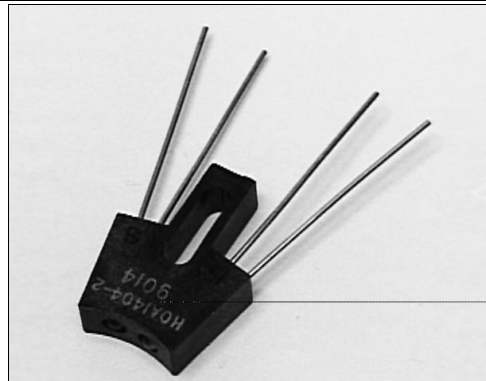


# HOA1404

## Reflective Sensor

### FEATURES

- Choice of phototransistor or photodarlington output
- Focused for maximum response
- Wide operating temperature range (-55°C to +100°C)



INFRA-61.TIF

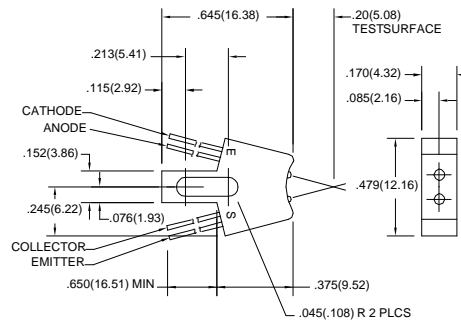
### DESCRIPTION

The HOA1404 series consists of an infrared emitting diode and an NPN silicon phototransistor (HOA1404-001,-002) or photodarlington (HOA1404-003), encased side-by-side on converging optical axes, in a black thermoplastic housing. The detector responds to radiation from the IRED only when a reflective object passes within its field of view. The HOA1404 series employs metal can packaged components. For additional component information see SE1450, SD1440, and SD1410.

Housing material is acetal copolymer. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

### OUTLINE DIMENSIONS in inches (mm)

Tolerance 3 plc decimals ±0.010(0.25)  
2 plc decimals ±0.020(0.51)



DIM\_037.d54

# HOA1404

## Reflective Sensor

### ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
<b>IR EMITTER</b>						
Forward Voltage	$V_F$			1.6	V	$I_F=20\text{ mA}$
Reverse Leakage Current	$I_R$			10	$\mu\text{A}$	$V_R=3\text{ V}$
<b>DETECTOR</b>						
Collector-Emitter Breakdown Voltage HOA1404-001, -002 HOA1404-003	$V_{(BR)CEO}$	30 15			V	$I_C=100\ \mu\text{A}$
Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	5.0			V	$I_E=100\ \mu\text{A}$
Collector Dark Current HOA1404-001, -002 HOA1404-003	$I_{CEO}$			100 250	nA	$V_{CE}=10\text{ V}$ $I_F=0$
<b>COUPLED CHARACTERISTICS</b>						
On-State Collector Current HOA1404-001 HOA1404-002 HOA1404-003	$I_{C(ON)}$	0.2 0.8 2.0			mA	$V_{CE}=5\text{ V}$ $I_F=30\text{ mA}$ (1)
Collector-Emitter Saturation Voltage HOA1404-001 HOA1404-002 HOA1404-003	$V_{CE(SAT)}$			0.4 0.4 1.1	V	$I_F=30\text{ mA}$ (1) $I_C=30\ \mu\text{A}$ $I_C=100\ \mu\text{A}$ $I_C=250\ \mu\text{A}$
Rise And Fall Time HOA1404-001, -002 HOA1404-003	$t_r, t_f$			15 75	$\mu\text{s}$	$V_{CC}=5\text{ V}, I_C=1\text{ mA}$ $R_L=1000\ \Omega$ $R_L=100\ \Omega$

Notes

1. Test surface is a front surface mirror (polished aluminum, 85% reflectance) located 0.20 in.(5.0 mm) from the front surface of the device.

### ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -55°C to 100°C

Storage Temperature Range -55°C to 125°C

Soldering Temperature (10 sec) 260°C

#### IR EMITTER

Power Dissipation 75 mW (1)

Reverse Voltage 3 V

Continuous Forward Current 50 mA

#### DETECTOR

Collector-Emitter Voltage 30 V

Emitter-Collector Voltage 5 V

Power Dissipation 75 mW (1) 75 mW (1)

Collector DC Current 30 mA 30 mA

#### TRANS. DARLINGTON

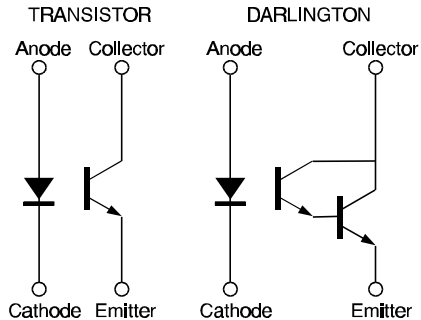
Collector-Emitter Voltage 15 V

Emitter-Collector Voltage 5 V

Power Dissipation 75 mW (1) 75 mW (1)

Collector DC Current 30 mA 30 mA

### SCHEMATIC



Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

# Honeywell

# HOA1404

## Reflective Sensor

Fig. 1 IRED Forward Bias Characteristics

gra\_073.ds4

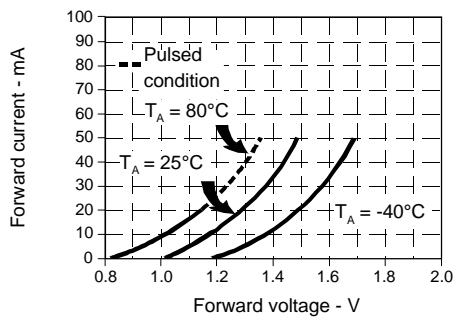


Fig. 2 Non-Saturated Switching Time vs Load Resistance

gra\_079.ds4

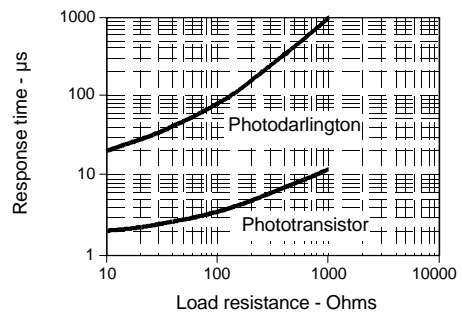


Fig. 3 Dark Current vs Temperature

gra\_303.cdr

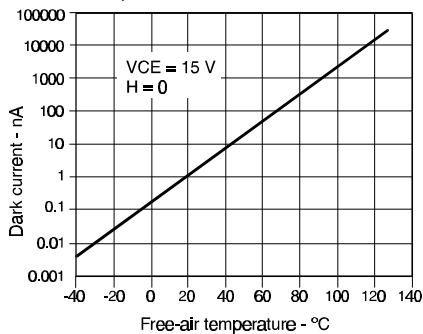


Fig. 4 Collector Current vs Ambient Temperature

gra\_076.ds4

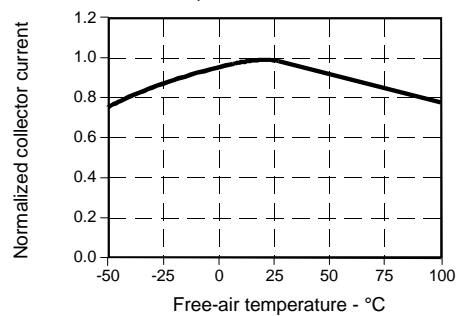


Fig. 5 Collector Current vs Distance to Reflective Surface

gra\_088.ds4

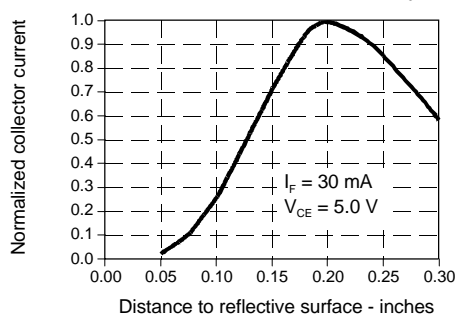
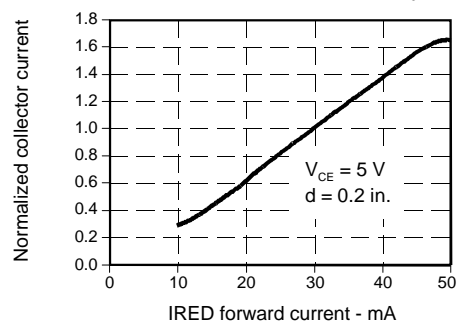


Fig. 6 Collector Current vs IRED Forward Current

gra\_089.ds4



All Performance Curves Show Typical Values

**HOA1404**  
Reflective Sensor

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